1 A, 40 V, Schottky Barrier Diode

These Schottky barrier diodes are optimized for low forward voltage drop and low leakage current and are offered in a Chip Scale Package (CSP) to reduce board space. The low thermal resistance enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Low Forward Voltage Drop 500 mV (Typ.) @ $I_F = 1.0 \text{ A}$
- Low Reverse Current $10 \mu A$ (Typ.) @ $V_R = 40 V$
- 1.0 A of Continuous Forward Current
- ESD Rating Human Body Model: Class 3B
 - Machine Model: Class C
- High Switching Speed
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	40	V
Forward Current (DC)	ΙF	1.0	Α
Forward Surge Current (60 Hz @ 1 cycle)	I _{FSM}	12	Α
Repetitive Peak Forward Current (Pulse Wave = 1 sec, Duty Cycle = 66%)	I _{FRM}	2.5	А
ESD Rating: Human Body Model Machine Model	ESD	> 8 > 400	kV V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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DSN2 (0402) CASE 152AE MARKING DIAGRAM

PIN 1

4NM

4N = Specific Device Code Y = Year Code

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping†
NSR10404NXT5G	DSN2 (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			260 480	°C/W mW
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			100 1.25	°C/W W
Storage Temperature Range	T _{stg}			-40 to +125	°C
Junction Temperature	TJ			+150	°C

- 1. Mounted onto a 4 in square FR-4 board 50 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.
- 2. Mounted onto a 4 in square FR-4 board 650 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

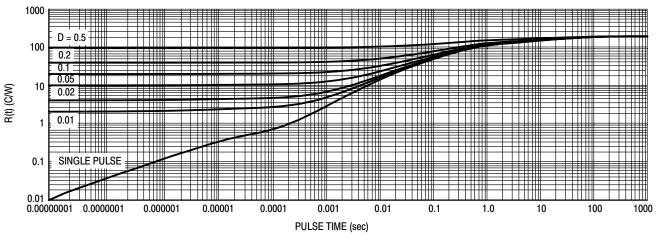


Figure 1. Thermal Response (Note 1)

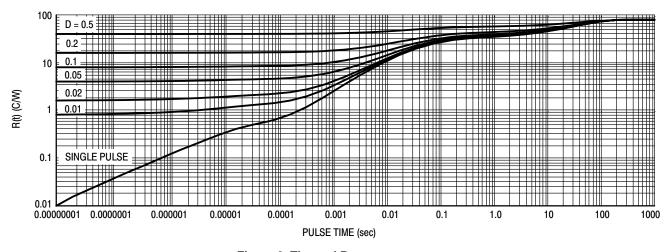
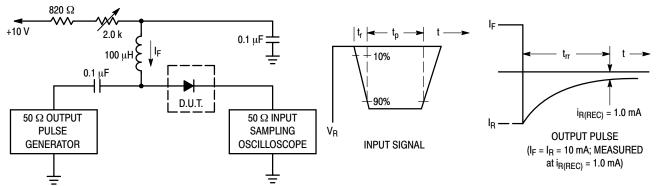


Figure 2. Thermal Response (Note 2)

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage (V _R = 10 V) (V _R = 40 V)	I _R	_ _	1.0 10	10 40	μΑ
Forward Voltage $ \begin{aligned} &(I_F = 0.1 \mu A) \\ &(I_F = 10 mA) \\ &(I_F = 100 mA) \\ &(I_F = 500 mA) \\ &(I_F = 1.0 A) \end{aligned} $	V _F	- - - - -	150 270 345 435 500	190 300 380 460 550	mV
Total Capacitance (V _R = 2.0 V, f = 1.0 MHz)	C _T	-	50	-	pF
Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}$, $I_{R(REC)} = 1.0 \text{ mA}$, Figure 3)	t _{rr}	-	20	-	ns
Peak Forward Recovery Voltage (I _F = 100 mA, t _r = 20 ns, Figure 4)	V_{FRM}	-	503	-	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA.

2. Input pulse is adjusted so I_{R(peak)} is equal to 10 mA.

3. t_p » t_{rr}

Figure 3. Recovery Time Equivalent Test Circuit

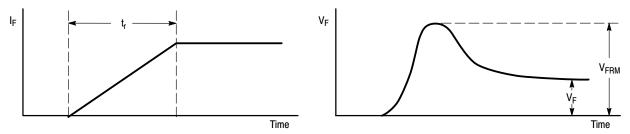


Figure 4. Peak Forward Recover Voltage Definition

TYPICAL CHARACTERISTICS

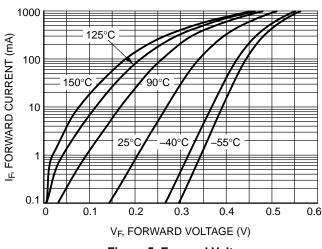
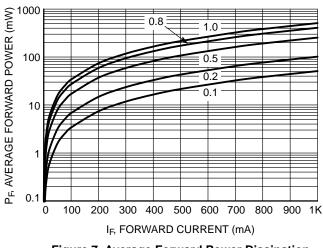


Figure 5. Forward Voltage

Figure 6. Leakage Current



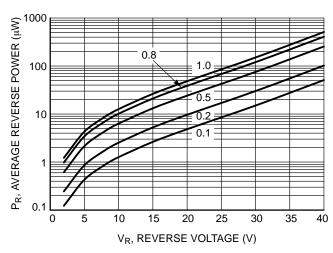
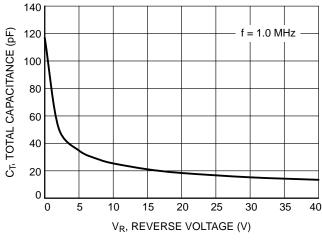


Figure 7. Average Forward Power Dissipation

Figure 8. Average Reverse Power Dissipation



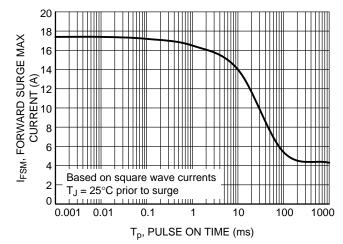


Figure 9. Total Capacitance

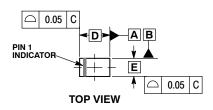
Figure 10. Forward Surge Maximum

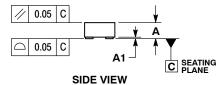


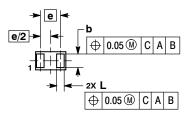


DSN2, 1.0x0.6, 0.65P, (0402) CASE 152AE **ISSUE A**

DATE 03 JUN 2016

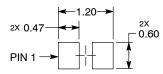






BOTTOM VIEW

RECOMMENDED **SOLDER FOOTPRINT***



DIMENSIONS: MILLIMETERS

See Application Note AND8398/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.25	0.31		
A1		0.05		
b	0.45	0.55		
D	1.00 BSC			
Е	0.60 BSC			
е	0.65 BSC			
1	0.20	0.30		

GENERIC MARKING DIAGRAM1*

GENERIC MARKING DIAGRAM2*





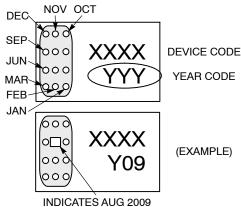
XXXX = Specific Device Code

XX = Specific Device Code M = Date Code

YYY = Year Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

CATHODE BAND MONTH CODING



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